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#### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "[Embedded - Microcontrollers](#)"

##### Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	83
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b520f2048iq100-br">https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b520f2048iq100-br</a>

## 3.7 Security Features

### 3.7.1 GPCRC (General Purpose Cyclic Redundancy Check)

The GPCRC module implements a Cyclic Redundancy Check (CRC) function. It supports both 32-bit and 16-bit polynomials. The supported 32-bit polynomial is 0x04C11DB7 (IEEE 802.3), while the 16-bit polynomial can be programmed to any value, depending on the needs of the application.

### 3.7.2 Crypto Accelerator (CRYPTO)

The Crypto Accelerator is a fast and energy-efficient autonomous hardware encryption and decryption accelerator. Giant Gecko Series 1 devices support AES encryption and decryption with 128- or 256-bit keys, ECC over both GF(P) and GF( $2^m$ ), and SHA-1 and SHA-2 (SHA-224 and SHA-256).

Supported block cipher modes of operation for AES include: ECB, CTR, CBC, PCBC, CFB, OFB, GCM, CBC-MAC, GMAC and CCM.

Supported ECC NIST recommended curves include P-192, P-224, P-256, K-163, K-233, B-163 and B-233.

The CRYPTO module allows fast processing of GCM (AES), ECC and SHA with little CPU intervention. CRYPTO also provides trigger signals for DMA read and write operations.

### 3.7.3 True Random Number Generator (TRNG)

The TRNG module is a non-deterministic random number generator based on a full hardware solution. The TRNG is validated with NIST800-22 and AIS-31 test suites as well as being suitable for FIPS 140-2 certification (for the purposes of cryptographic key generation).

## 3.8 Analog

### 3.8.1 Analog Port (APORT)

The Analog Port (APORT) is an analog interconnect matrix allowing access to many analog modules on a flexible selection of pins. Each APORT bus consists of analog switches connected to a common wire. Since many clients can operate differentially, buses are grouped by X/Y pairs.

### 3.8.2 Analog Comparator (ACMP)

The Analog Comparator is used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. Inputs are selected from among internal references and external pins. The tradeoff between response time and current consumption is configurable by software. Two 6-bit reference dividers allow for a wide range of internally-programmable reference sources. The ACMP can also be used to monitor the supply voltage. An interrupt can be generated when the supply falls below or rises above the programmable threshold.

### 3.8.3 Analog to Digital Converter (ADC)

The ADC is a Successive Approximation Register (SAR) architecture, with a resolution of up to 12 bits at up to 1 Msps. The output sample resolution is configurable and additional resolution is possible using integrated hardware for averaging over multiple samples. The ADC includes integrated voltage references and an integrated temperature sensor. Inputs are selectable from a wide range of sources, including pins configurable as either single-ended or differential.

### 3.12 Configuration Summary

The features of the EFM32GG11 are a subset of the feature set described in the device reference manual. The table below describes device specific implementation of the features. Remaining modules support full configuration.

**Table 3.2. Configuration Summary**

Module	Configuration	Pin Connections
USART0	IrDA, SmartCard	US0_TX, US0_RX, US0_CLK, US0_CS
USART1	I <sup>2</sup> S, SmartCard	US1_TX, US1_RX, US1_CLK, US1_CS
USART2	IrDA, SmartCard, High-Speed	US2_TX, US2_RX, US2_CLK, US2_CS
USART3	I <sup>2</sup> S, SmartCard	US3_TX, US3_RX, US3_CLK, US3_CS
USART4	I <sup>2</sup> S, SmartCard	US4_TX, US4_RX, US4_CLK, US4_CS
USART5	SmartCard	US5_TX, US5_RX, US5_CLK, US5_CS
TIMER0	with DTI	TIM0_CC[2:0], TIM0_CDTI[2:0]
TIMER1	-	TIM1_CC[3:0]
TIMER2	with DTI	TIM2_CC[2:0], TIM2_CDTI[2:0]
TIMER3	-	TIM3_CC[2:0]
TIMER4	with DTI	TIM4_CC[2:0], TIM4_CDTI[2:0]
TIMER5	-	TIM5_CC[2:0]
TIMER6	with DTI	TIM6_CC[2:0], TIM6_CDTI[2:0]
WTIMER0	with DTI	WTIM0_CC[2:0], WTIM0_CDTI[2:0]
WTIMER1	-	WTIM1_CC[3:0]
WTIMER2	-	WTIM2_CC[2:0]
WTIMER3	-	WTIM3_CC[2:0]

#### 4.1.4 DC-DC Converter

Test conditions: L\_DCDC=4.7  $\mu$ H (Murata LQH3NPN4R7MM0L), C\_DCDC=4.7  $\mu$ F (Samsung CL10B475KQ8NQNC), V\_DCDC\_I=3.3 V, V\_DCDC\_O=1.8 V, I\_DCDC\_LOAD=50 mA, Heavy Drive configuration, F\_DCDC\_LN=7 MHz, unless otherwise indicated.

**Table 4.4. DC-DC Converter**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input voltage range	V <sub>DCDC_I</sub>	Bypass mode, I <sub>DCDC_LOAD</sub> = 50 mA	1.8	—	V <sub>VREGVDD_MAX</sub>	V
		Low noise (LN) mode, 1.8 V output, I <sub>DCDC_LOAD</sub> = 100 mA, or Low power (LP) mode, 1.8 V output, I <sub>DCDC_LOAD</sub> = 10 mA	2.4	—	V <sub>VREGVDD_MAX</sub>	V
		Low noise (LN) mode, 1.8 V output, I <sub>DCDC_LOAD</sub> = 200 mA	2.6	—	V <sub>VREGVDD_MAX</sub>	V
Output voltage programmable range <sup>1</sup>	V <sub>DCDC_O</sub>		1.8	—	V <sub>VREGVDD</sub>	V
Regulation DC accuracy	ACC <sub>DC</sub>	Low Noise (LN) mode, 1.8 V target output	TBD	—	TBD	V
Regulation window <sup>4</sup>	WIN <sub>REG</sub>	Low Power (LP) mode, LPCMPBIASEMxx <sup>3</sup> = 0, 1.8 V target output, I <sub>DCDC_LOAD</sub> $\leq$ 75 $\mu$ A	TBD	—	TBD	V
		Low Power (LP) mode, LPCMPBIASEMxx <sup>3</sup> = 3, 1.8 V target output, I <sub>DCDC_LOAD</sub> $\leq$ 10 mA	TBD	—	TBD	V
Steady-state output ripple	V <sub>R</sub>		—	3	—	mVpp
Output voltage under/overshoot	V <sub>Ov</sub>	CCM Mode (LNFORCECCM <sup>3</sup> = 1), Load changes between 0 mA and 100 mA	—	25	TBD	mV
		DCM Mode (LNFORCECCM <sup>3</sup> = 0), Load changes between 0 mA and 10 mA	—	45	TBD	mV
		Overshoot during LP to LN CCM/DCM mode transitions compared to DC level in LN mode	—	200	—	mV
		Undershoot during BYP/LP to LN CCM (LNFORCECCM <sup>3</sup> = 1) mode transitions compared to DC level in LN mode	—	40	—	mV
		Undershoot during BYP/LP to LN DCM (LNFORCECCM <sup>3</sup> = 0) mode transitions compared to DC level in LN mode	—	100	—	mV
DC line regulation	V <sub>REG</sub>	Input changes between V <sub>VREGVDD_MAX</sub> and 2.4 V	—	0.1	—	%
DC load regulation	I <sub>REG</sub>	Load changes between 0 mA and 100 mA in CCM mode	—	0.1	—	%

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output fall time, From 70% to 30% of $V_{IO}$	$t_{IOOF}$	$C_L = 50 \text{ pF}$ , DRIVESTRENGTH <sup>1</sup> = STRONG, SLEWRATE <sup>1</sup> = 0x6	—	1.8	—	ns
		$C_L = 50 \text{ pF}$ , DRIVESTRENGTH <sup>1</sup> = WEAK, SLEWRATE <sup>1</sup> = 0x6	—	4.5	—	ns
Output rise time, From 30% to 70% of $V_{IO}$	$t_{IOOR}$	$C_L = 50 \text{ pF}$ , DRIVESTRENGTH <sup>1</sup> = STRONG, SLEWRATE = 0x6 <sup>1</sup>	—	2.2	—	ns
		$C_L = 50 \text{ pF}$ , DRIVESTRENGTH <sup>1</sup> = WEAK, SLEWRATE <sup>1</sup> = 0x6	—	7.4	—	ns

**Note:**

1. In GPIO\_Pn\_CTRL register.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Note:</b>						
1.	ACMPVDD	is a supply chosen by the setting in ACMPn_CTRL_PWRSEL and may be IOVDD, AVDD or DVDD.				
2.		The total ACMP current is the sum of the contributions from the ACMP and its internal voltage reference. $I_{ACMPTOTAL} = I_{ACMP} + I_{ACMPREF}$ .				
3.		$\pm 100$ mV differential drive.				
4.		In ACMPn_CTRL register.				
5.		In ACMPn_HYSTERESIS registers.				
6.		In ACMPn_INPUTSEL register.				

4.1.23.2 I2C Fast-mode (Fm)<sup>1</sup>Table 4.32. I2C Fast-mode (Fm)<sup>1</sup>

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency <sup>2</sup>	f <sub>SCL</sub>		0	—	400	kHz
SCL clock low time	t <sub>LOW</sub>		1.3	—	—	μs
SCL clock high time	t <sub>HIGH</sub>		0.6	—	—	μs
SDA set-up time	t <sub>SU_DAT</sub>		100	—	—	ns
SDA hold time <sup>3</sup>	t <sub>HD_DAT</sub>		100	—	900	ns
Repeated START condition set-up time	t <sub>SU_STA</sub>		0.6	—	—	μs
(Repeated) START condition hold time	t <sub>HD_STA</sub>		0.6	—	—	μs
STOP condition set-up time	t <sub>SU_STO</sub>		0.6	—	—	μs
Bus free time between a STOP and START condition	t <sub>BUF</sub>		1.3	—	—	μs

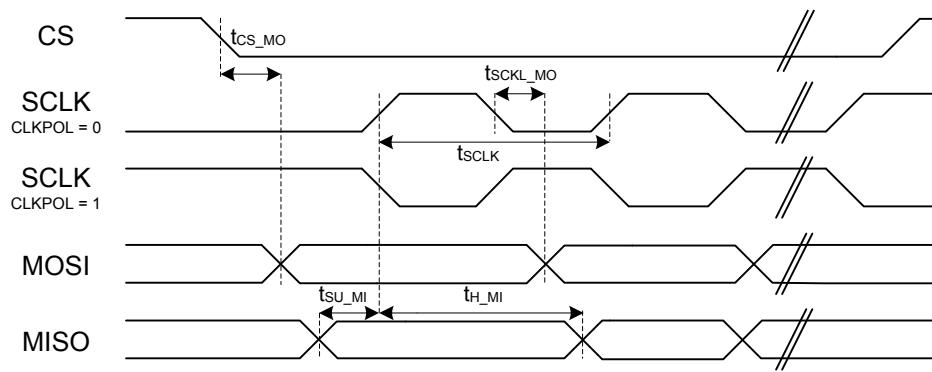
**Note:**

1. For CLHR set to 1 in the I2Cn\_CTRL register.
2. For the minimum HFFPERCLK frequency required in Fast-mode, refer to the I2C chapter in the reference manual.
3. The maximum SDA hold time (t<sub>HD,DAT</sub>) needs to be met only when the device does not stretch the low time of SCL (t<sub>LOW</sub>).

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
MISO hold time <sup>1 3</sup>	$t_{H\_MI}$	USART2, location 4, IOVDD = 1.8 V	-11.6	—	—	ns
		USART2, location 4, IOVDD = 3.0 V	-11.6	—	—	ns
		USART2, location 5, IOVDD = 1.8 V	-9.1	—	—	ns
		USART2, location 5, IOVDD = 3.0 V	-9.1	—	—	ns
		All other USARTs and locations, IOVDD = 1.8 V	-8	—	—	ns
		All other USARTs and locations, IOVDD = 3.0 V	-8	—	—	ns

**Note:**

1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).
2.  $t_{HPERCLK}$  is one period of the selected HPERCLK.
3. Measurement done with 8 pF output loading at 10% and 90% of  $V_{DD}$  (figure shows 50% of  $V_{DD}$ ).

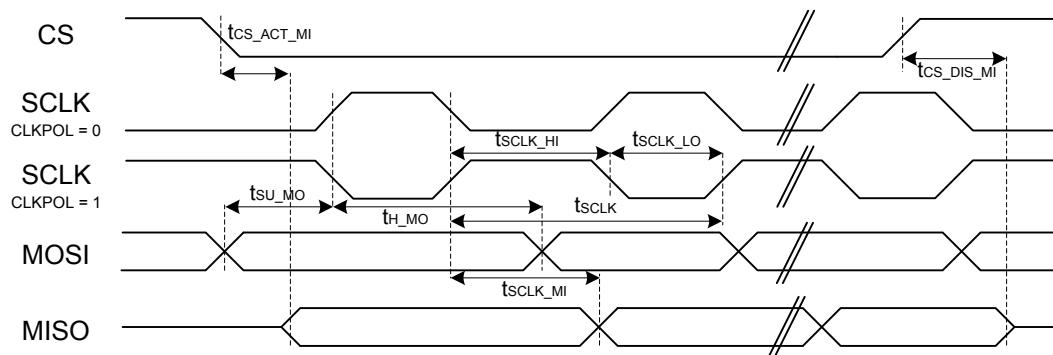
**Figure 4.1. SPI Master Timing Diagram**

**SPI Slave Timing****Table 4.35. SPI Slave Timing**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCLK period <sup>1 3 2</sup>	t <sub>SCLK</sub>		6 * t <sub>HFPERCLK</sub>	—	—	ns
SCLK high time <sup>1 3 2</sup>	t <sub>SCLK_HI</sub>		2.5 * t <sub>HFPERCLK</sub>	—	—	ns
SCLK low time <sup>1 3 2</sup>	t <sub>SCLK_LO</sub>		2.5 * t <sub>HFPERCLK</sub>	—	—	ns
CS active to MISO <sup>1 3</sup>	t <sub>CS_ACT_MI</sub>		24	—	69	ns
CS disable to MISO <sup>1 3</sup>	t <sub>CS_DIS_MI</sub>		19	—	175	ns
MOSI setup time <sup>1 3</sup>	t <sub>SU_MO</sub>		7	—	—	ns
MOSI hold time <sup>1 3 2</sup>	t <sub>H_MO</sub>		6	—	—	ns
SCLK to MISO <sup>1 3 2</sup>	t <sub>SCLK_MI</sub>		16 + 1.5 * t <sub>HFPERCLK</sub>	—	43 + 2.5 * t <sub>HFPERCLK</sub>	ns

**Note:**

1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).
2. t<sub>HFPERCLK</sub> is one period of the selected HFPERCLK.
3. Measurement done with 8 pF output loading at 10% and 90% of V<sub>DD</sub> (figure shows 50% of V<sub>DD</sub>).

**Figure 4.2. SPI Slave Timing Diagram**

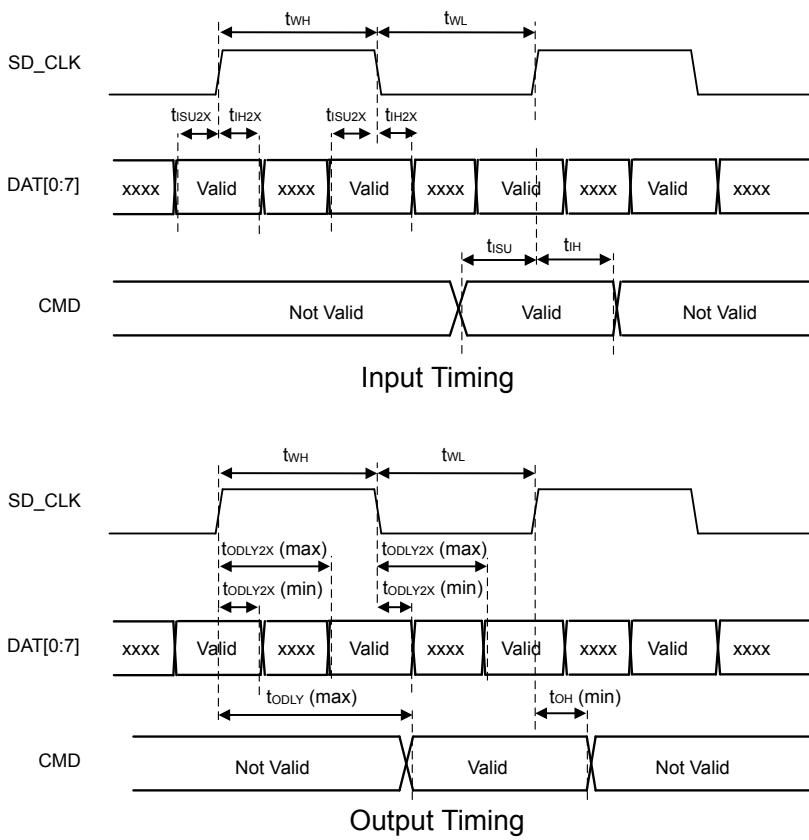


Figure 4.20. SDIO MMC DDR Mode Timing

#### 4.1.28 Quad SPI (QSPI)

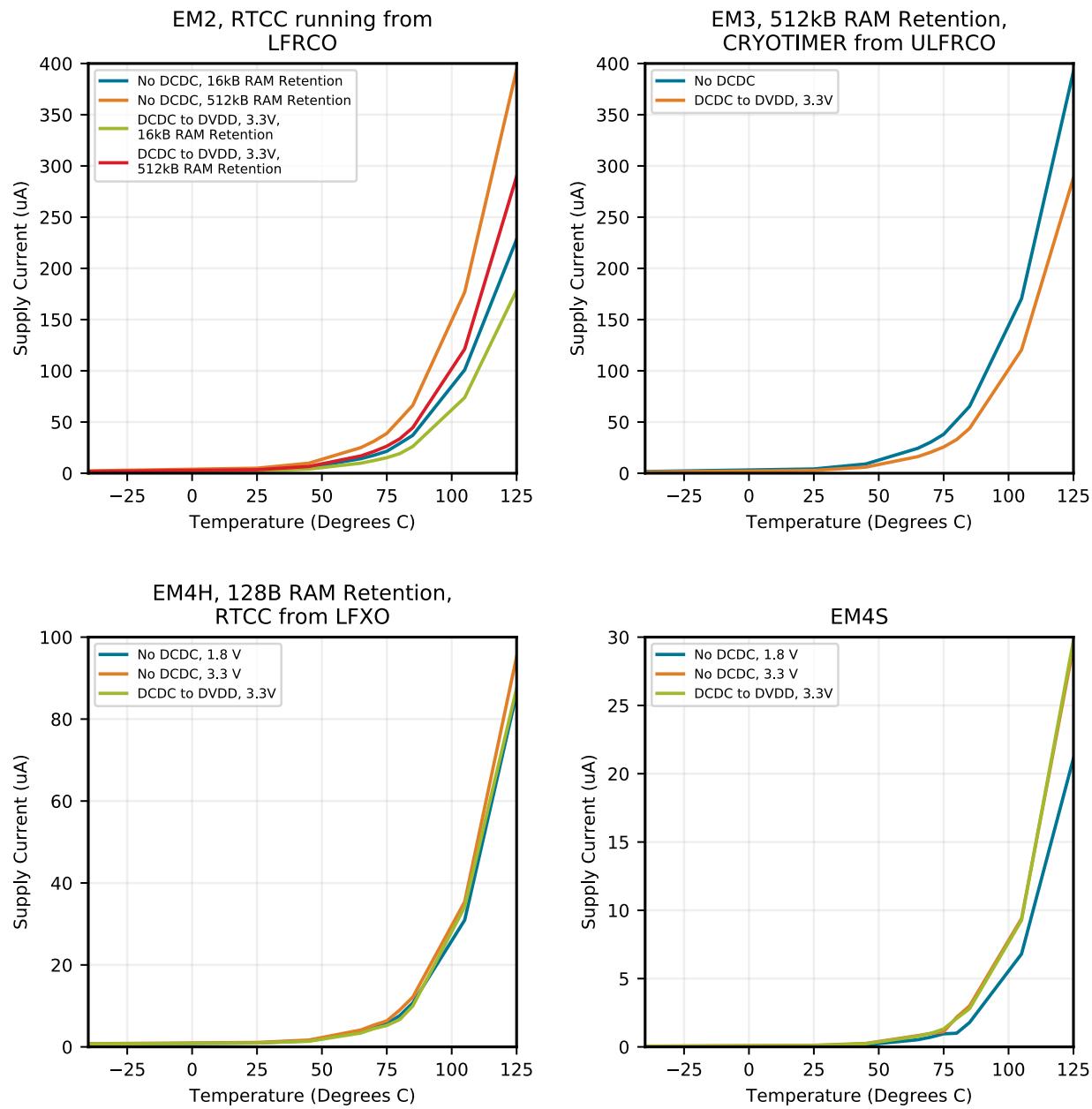
##### 4.1.28.1 QSPI SDR Mode

###### QSPI SDR Mode Timing (Location 0)

Timing is specified with voltage scaling disabled, PHY-mode, route location 0 only, TX DLL = 23, RX DLL = 48, 20-25 pF loading per GPIO, and slew rate for all GPIO set to 6, DRIVESTRENGTH = STRONG.

Table 4.54. QSPI SDR Mode Timing (Location 0)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Full SCLK period	T		$(1/F_{SCLK}) * 0.95$	—	—	ns
Output valid	tov		—	—	T/2 - 2.4	ns
Output hold	toH		T/2 - 32.9	—	—	ns
Input setup	tsu		36.2 - T/2	—	—	ns
Input hold	tH		T/2 - 3.3	—	—	ns



**Figure 4.26. EM2, EM3, EM4H and EM4S Typical Supply Current vs. Temperature**

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
IOVDD1	F7 G7	Digital IO power supply 1.	VSS	F8 G8 G9 H6 H7 H8 H9 H10 H11 J6 J7 J8 J9 J10 J11 K8 K9 L8 L9	Ground
NC	F9	No Connect.	IOVDD0	F10 F11 G10 G11 K6 K7 K10 K11 L6 L7 L10 L11	Digital IO power supply 0.
PI5	F14	GPIO (5V)	PI4	F15	GPIO (5V)
PI3	F16	GPIO (5V)	PA5	G1	GPIO
PG6	G2	GPIO (5V)	PG5	G3	GPIO (5V)
PI2	G14	GPIO (5V)	PI1	G15	GPIO (5V)
PI0	G16	GPIO (5V)	PA6	H1	GPIO
PG8	H2	GPIO (5V)	PG7	H3	GPIO (5V)
PE5	H14	GPIO	PE6	H15	GPIO
PE7	H16	GPIO	PG11	J1	GPIO (5V)
PG10	J2	GPIO (5V)	PG9	J3	GPIO (5V)
PE3	J14	GPIO	PE4	J15	GPIO
DECOPPLE	J16	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PG14	K1	GPIO
PG13	K2	GPIO	PG12	K3	GPIO
PE1	K14	GPIO (5V)	PE2	K15	GPIO
DVDD	K16	Digital power supply.	PG15	L1	GPIO (5V)
PB15	L2	GPIO (5V)	PB0	L3	GPIO
PE0	L14	GPIO (5V)	PC7	L15	GPIO
VREGVDD	L16	Voltage regulator VDD input	PB1	M1	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PF11	A13	GPIO (5V)	PA15	B1	GPIO
PE13	B2	GPIO	PE11	B3	GPIO
PE8	B4	GPIO	PD12	B5	GPIO
PD10	B6	GPIO	PF8	B7	GPIO
PF6	B8	GPIO	PF3	B9	GPIO
PF1	B10	GPIO (5V)	PF12	B11	GPIO
VBUS	B12	USB VBUS signal and auxiliary input to 5 V regulator.	PF10	B13	GPIO (5V)
PA1	C1	GPIO	PA0	C2	GPIO
PE10	C3	GPIO	PD13	C4	GPIO (5V)
VSS	C5 C8 H3 J3 K11 K12 L12 L13 M8 M11 N8	Ground	IOVDD1	C6	Digital IO power supply 1.
PF9	C7	GPIO	IOVDD0	C9 J11 K3 L11 L14	Digital IO power supply 0.
PF0	C10	GPIO (5V)	PE4	C11	GPIO
PC14	C12	GPIO (5V)	PC15	C13	GPIO (5V)
PA3	D1	GPIO	PA2	D2	GPIO
PB15	D3	GPIO (5V)	PE5	D11	GPIO
PC12	D12	GPIO (5V)	PC13	D13	GPIO (5V)
PA6	E1	GPIO	PA5	E2	GPIO
PA4	E3	GPIO	PE6	E11	GPIO
PC10	E12	GPIO (5V)	PC11	E13	GPIO (5V)
PB0	F1	GPIO	PB1	F2	GPIO
PB2	F3	GPIO	PE7	F11	GPIO
PC8	F12	GPIO (5V)	PC9	F13	GPIO (5V)
PB3	G1	GPIO	PB4	G2	GPIO
IOVDD2	G3	Digital IO power supply 2.	PE0	G11	GPIO (5V)
PE1	G12	GPIO (5V)	PE3	G13	GPIO
PB5	H1	GPIO	PB6	H2	GPIO
DVDD	H11	Digital power supply.	PE2	H12	GPIO
PC7	H13	GPIO	PD14	J1	GPIO (5V)

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PE6	BUSDY BUSCX LCD_COM2	EBI_A13 #0 EBI_A18 #1 EBI_A24 #3	TIM3_CC1 #3 TIM5_CC2 #0 TIM6_CDTI2 #2 WTIMO_CC2 #0 WTIM1_CC3 #4	US0_RX #1 US3_TX #1	PRS_CH6 #2
PE7	BUSCY BUSDX LCD_COM3	EBI_A14 #0 EBI_A19 #1 EBI_A25 #3	TIM3_CC2 #3 TIM5_CC0 #1 WTIM1_CC0 #5	US0_TX #1 US3_RX #1	PRS_CH7 #2
PG11		EBI_AD11 #2	TIM6_CDTI2 #1 WTIMO_CDTI0 #3	ETH_MIIRXD0 #1 CAN1_TX #6 US3 RTS #5 QSPI0_DQS #2	ETM_TD3 #5
PG10		EBI_AD10 #2	TIM2_CC2 #6 TIM6_CDTI1 #1 WTIMO_CC2 #3	ETH_MIIRXD1 #1 CAN1_RX #6 US3_CTS #3 QSPI0_CS1 #2	
PG9		EBI_AD09 #2	TIM2_CC1 #6 TIM6_CDTI0 #1 WTIMO_CC1 #3	ETH_MIIRXD2 #1 CAN0_TX #4 US3_CTS #5 QSPI0_CS0 #2	
PE3	BU_STAT	EBI_A10 #0 EBI_A15 #1	TIM3_CC0 #2 WTIM1_CC0 #4	US0_CTS #1 U0_RTS #1 U1_RX #3	ACMP1_O #1
PE4	BUSDY BUSCX LCD_COM0	EBI_A11 #0 EBI_A16 #1 EBI_A22 #3	TIM3_CC1 #2 TIM5_CC0 #0 TIM6_CDTI0 #2 WTIMO_CC0 #0 WTIM1_CC1 #4	US0_CS #1 US1_CS #5 US3_CS #1 U0_RX #6 U1_CTS #3 I2C0_SDA #7	PRS_CH16 #2
PG14		EBI_AD14 #2	TIM6_CC2 #2 WTIM2_CC0 #4 PCNT1_S0IN #7	ETH_MIICRS #1 US0_CLK #6	ETM_TD0 #5
PG13		EBI_AD13 #2	TIM6_CC1 #2 WTIMO_CDTI2 #3 WTIM2_CC2 #3	ETH_MIIRXER #1 US0_RX #6	ETM_TD1 #5
PG12		EBI_AD12 #2	TIM6_CC0 #2 WTIMO_CDTI1 #3 WTIM2_CC1 #3	ETH_MIIRXDV #1 US0_TX #6	ETM_TD2 #5
PE1	BUSCY BUSDX	EBI_A01 #2 EBI_A08 #0	TIM3_CC1 #1 WTIM1_CC2 #3 PCNT0_S1IN #1	CAN0_TX #6 U0_RX #1 I2C1_SCL #2	CMU_CLKI0 #4 PRS_CH23 #1 ACMP2_O #2
PE2	BU_VOUT	EBI_A09 #0 EBI_A14 #1	TIM3_CC2 #1 WTIM1_CC3 #3	US0_RTS #1 U0_CTS #1 U1_TX #3	PRS_CH20 #2 ACMP0_O #1
PG15		EBI_AD15 #2	WTIM2_CC1 #4 PCNT1_S1IN #7	ETH_MIICOL #1 US0_CS #6	ETM_TCLK #5
PB15	BUSAY BUSBX	EBI_CS3 #1 EBI_AR-DY #2	TIM3_CC1 #7	ETH_TSUTMRTOG #1 SDIO_WP #2 US2_RTS #1 US5_RTS #1	PRS_CH17 #1 ETM_TD2 #1

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PH11	BUSACMP3Y BU-SACMP3X	EBI_A23 #2	TIM5_CC1 #1 WTIM1_CC3 #6	US5_RX #3 U1_TX #5 I2C1_SDA #5	
PH13	BUSACMP3Y BU-SACMP3X	EBI_A25 #2	TIM5_CC0 #2 WTIM1_CC1 #7 PCNT2_S1IN #7	US5_CS #3 U1_CTS #5 I2C1_SDA #6	
PD0	VDAC0_OUT0ALT / OPA0_OUTALT #4 OPA2_OUTALT BU-SADC0Y BUSADC0X	EBI_A04 #1 EBI_A13 #3	TIM4_CDTI0 TIM6_CC2 #5 WTIM1_CC2 #0 PCNT2_S0IN #0	CAN0_RX #2 US1_TX #1	
PD3	BUSADC0Y BU-SADC0X OPA2_N	EBI_A07 #1 EBI_A16 #3	TIM4_CDTI2 TIM0_CC2 #2 TIM6_CC2 #6 WTIM1_CC1 #1 WTIM2_CC0 #5	CAN1_RX #2 US1_CS #1 LEU1_RX #2	ETM_TD1 #0 ETM_TD1 #2
PD8	BU_VIN	EBI_A12 #1	WTIM1_CC2 #2	US2_RTS #5	CMU_CLK1 #1 PRS_CH12 #2 ACMP2_O #0
PB7	LFXTAL_P		TIM0_CDTI0 #4 TIM1_CC0 #3	US0_TX #4 US1_CLK #0 US3_RX #2 US4_TX #0 U0_CTS #4	PRS_CH22 #0
PC3	VDAC0_OUT0ALT / OPA0_OUTALT #3 BUSACMP0Y BU-SACMP0X	EBI_AD10 #1 EBI_CS3 #2 EBI_BL1 #3 EBI_NANDREn #0	TIM0_CDTI1 #3 TIM2_CC1 #5 WTIM0_CC2 #7 LE-TIM1_OUT1 #3	ETH_TSUTMRTOG #2 CAN1_TX #0 US1_CLK #4 US2_RX #0	LES_CH3 PRS_CH11 #1
PC5	BUSACMP0Y BU-SACMP0X OPA0_N	EBI_AD12 #1 EBI_WEn #2 EBI_NANDWE #0 EBI_A00 #3	TIM0_CC1 #5 LE-TIM0_OUT1 #3 PCNT1_S1IN #3	SDIO_WP #1 US2_CS #0 US4_CS #0 U0_RX #4 U1_RTS #4 I2C1_SCL #0	LES_CH5 PRS_CH19 #2
PA9	BUSAY BUSBX LCD_SEG37	EBI_AD15 #1 EBI_A03 #3 EBI_DTE #0	TIM2_CC1 #0 TIM0_CC1 #6 WTIM2_CC0 #0 LE-TIM0_OUT1 #6	US2_CLK #2	PRS_CH9 #0
PB10	BUSBY BUSAX	EBI_BL0 #2 EBI_A01 #1 EBI_A04 #0 EBI_A10 #3	WTIM2_CC1 #2 LE-TIM0_OUT1 #7	SDIO_CD #3 CAN0_TX #3 US1_RTS #0 US2_CTS #3 U1_RX #2	PRS_CH9 #2 ACMP1_O #6
PH0	BUSADC1Y BU-SADC1X	EBI_DCLK #2	WTIM2_CC2 #4	US0_CTS #6 LEU1_TX #5	
PH3	BUSADC1Y BU-SADC1X	EBI_HSNC #2	TIM6_CC1 #3	US1_RTS #6	
PH6	BUSADC1Y BU-SADC1X	EBI_A18 #2	TIM6_CDTI1 #3 WTIM2_CC2 #6	US4_CLK #4	
PH9	BUSACMP3Y BU-SACMP3X	EBI_A21 #2	TIM6_CC1 #4 WTIM1_CC1 #6 WTIM2_CC2 #7	US4_RTS #4	
PH12	BUSACMP3Y BU-SACMP3X	EBI_A24 #2	TIM5_CC2 #1 WTIM1_CC0 #7	US5_CLK #3 U1_RX #5 I2C1_SCL #5	

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
EBI_AD08	0: PA15 1: PC1 2: PG8		External Bus Interface (EBI) address and data input / output pin 08.
EBI_AD09	0: PA0 1: PC2 2: PG9		External Bus Interface (EBI) address and data input / output pin 09.
EBI_AD10	0: PA1 1: PC3 2: PG10		External Bus Interface (EBI) address and data input / output pin 10.
EBI_AD11	0: PA2 1: PC4 2: PG11		External Bus Interface (EBI) address and data input / output pin 11.
EBI_AD12	0: PA3 1: PC5 2: PG12		External Bus Interface (EBI) address and data input / output pin 12.
EBI_AD13	0: PA4 1: PA7 2: PG13		External Bus Interface (EBI) address and data input / output pin 13.
EBI_AD14	0: PA5 1: PA8 2: PG14		External Bus Interface (EBI) address and data input / output pin 14.
EBI_AD15	0: PA6 1: PA9 2: PG15		External Bus Interface (EBI) address and data input / output pin 15.
EBI_ALE	0: PF3 1: PB9 2: PC4 3: PB5	4: PC11 5: PC11	External Bus Interface (EBI) Address Latch Enable output.
EBI_ARDY	0: PF2 1: PD13 2: PB15 3: PB4	4: PC13 5: PF10	External Bus Interface (EBI) Hardware Ready Control input.
EBI_BL0	0: PF6 1: PF8 2: PB10 3: PC1	4: PF6 5: PF6	External Bus Interface (EBI) Byte Lane/Enable pin 0.
EBI_BL1	0: PF7 1: PF9 2: PB11 3: PC3	4: PF7 5: PF7	External Bus Interface (EBI) Byte Lane/Enable pin 1.
EBI_CS0	0: PD9 1: PA10 2: PC0 3: PB0	4: PE8	External Bus Interface (EBI) Chip Select output 0.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
US5_RX	0: PE9 1: PA7 2: PB1 3: PH11		USART5 Asynchronous Receive. USART5 Synchronous mode Master Input / Slave Output (MISO).
US5_TX	0: PE8 1: PA6 2: PF15 3: PH10		USART5 Asynchronous Transmit. Also used as receive input in half duplex communication. USART5 Synchronous mode Master Output / Slave Input (MOSI).
USB_DM	0: PF10		USB D- pin.
USB_DP	0: PF11		USB D+ pin.
USB_ID	0: PF12		USB ID pin.
USB_VBUSEN	0: PF5		USB 5 V VBUS enable.
VDAC0_EXT	0: PD6		Digital to analog converter VDAC0 external reference input pin.
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.
WTIM0_CC0	0: PE4 1: PA6 2: PG2 3: PG8	4: PC15 5: PB0 6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.
WTIM0_CC1	0: PE5 1: PD13 2: PG3 3: PG9	4: PF0 5: PB1 6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.

Table 5.24. ACMP1 Bus and Pin Mapping

	APORT4Y	APORT4X	APORT3Y	APORT3X	APORT2Y	APORT2X	APORT1Y	APORT1X	APORT0Y	APORT0X	Port
BUSDY	BUSDX	BUSCY	BUSCX	BUSBY	BUSBX	BUSAY	BUSAX	BUSACMP1Y	BUSACMP1X	BUS	CH31
PF15	PF15			PB15		PB15					CH30
PF14		PF14		PB14			PB14				CH29
PF12		PF12		PB12		PB13	PB13				CH28
PF10		PF11	PF13	PB10	PB11	PB11	PB12				CH27
PF8		PF9	PF9	PB9	PB9	PB9	PB10				CH26
PF6		PF7	PF7	PB6	PB6	PB6	PB6				CH25
PF4		PF5	PF5	PB4	PB4	PB5	PB5	PB4			CH24
PF2		PF3	PF3	PB2	PB2	PB3	PB3	PB2			CH23
PF0		PF1	PF1	PB0	PB0	PB1	PB1	PB0			CH22
PE14		PE15	PE15	PA14	PA14	PA15	PA15	PA14			CH20
PE12		PE13	PE13	PA12	PA12	PA13	PA13	PA12			CH19
PE10		PE11	PE11	PA10	PA10	PA11	PA11	PA10			CH18
PE8		PE9	PE9	PA8	PA8	PA9	PA9	PA8			CH17
PE6		PE7	PE7	PA6	PA6	PA5	PA5	PA6	PC14	PC14	CH16
PE4		PE5	PE5	PA4	PA4	PA3	PA3	PA4	PC13	PC13	CH15
				PA2		PA2		PA2	PC12	PC12	CH14
		PE1	PE1	PA1	PA1	PA1	PA1	PA0	PC11	PC11	CH13
PE0			PE0	PA0					PC10	PC10	CH12
									PC9	PC9	CH11
									PC8	PC8	CH10

**Table 7.1. BGA152 Package Dimensions**

<b>Dimension</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>
A	0.78	0.84	0.90
A1	0.13	0.18	0.23
A3	0.16	0.20	0.24
A2		0.45 REF	
D		8.00 BSC	
e		0.50 BSC	
E		8.00 BSC	
D1		6.50 BSC	
E1		6.50 BSC	
b	0.20	0.25	0.30
aaa		0.10	
bbb		0.10	
ddd		0.08	
eee		0.15	
fff		0.05	

**Note:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

**Table 8.2. BGA120 PCB Land Pattern Dimensions**

Dimension	Min	Nom	Max
X		0.20	
C1		6.00	
C2		6.00	
E1		0.5	
E2		0.5	

**Note:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size should be 1:1.
8. A No-Clean, Type-3 solder paste is recommended.
9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

## 10.2 TQFP100 PCB Land Pattern

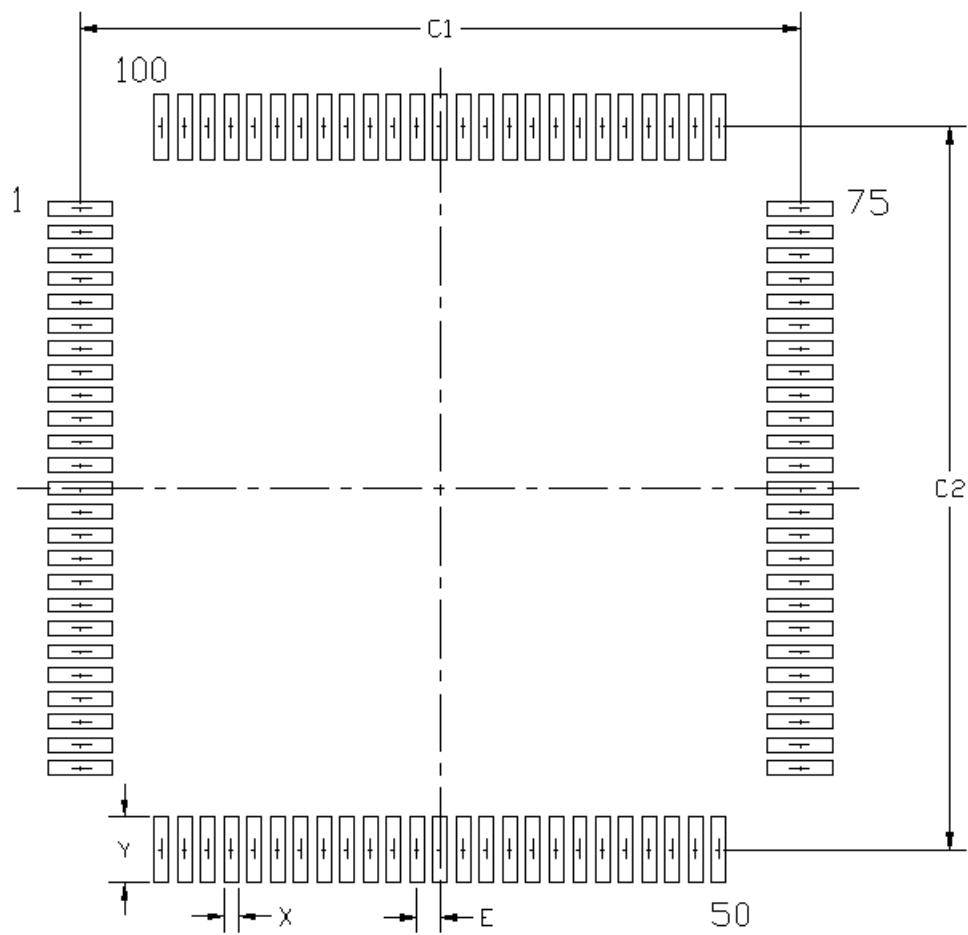


Figure 10.2. TQFP100 PCB Land Pattern Drawing